

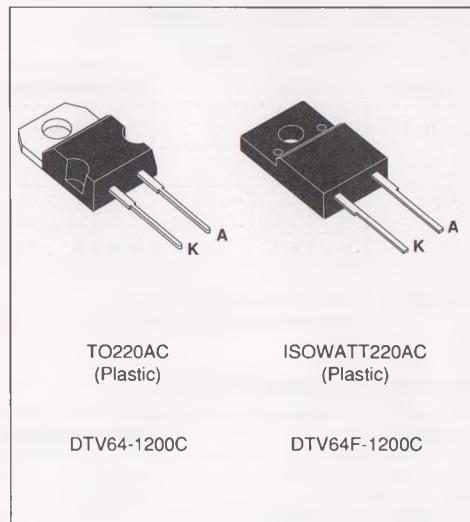


FEATURES

- HIGH BREAKDOWN VOLTAGE CAPABILITY
- MEDIUM & HIGH FREQUENCY OPERATION
- SPECIFIED TURN ON SWITCHING CHARACTERISTICS
- TYPICAL TOTAL LOSSES : 3 W
($I_{Fpeak} = 6\text{ A}$, $F = 64\text{ kHz}$)
- SUITABLE WITH **BUH** TRANSISTORS SERIES
- INSULATED VERSION (ISOWATT220AC) :
Insulating voltage = 2000 V DC
Capacitance = 12 pF

DESCRIPTION

High voltage diode especially designed for horizontal deflection stage in standard and high resolution displays for TV's and monitors.
This device is packaged in TO220AC or ISO-WATT220AC.



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter			Value	Unit
V_{RRM}	Repetitive peak reverse voltage			1200	V
V_{RWM}	Repetitive working voltage			1200	V
$I_F(\text{RMS})$	RMS forward current			20	A
$I_F(\text{AV})$	$\delta = 0.5$	TO220AC	$T_c=120^\circ\text{C}$	6	A
		ISOWATT220AC	$T_c=90^\circ\text{C}$	6	
I_{FSM}	Surge non repetitive forward current		$t_p=10\text{ms}$ sinusoidal	100	A
T_{stg} T_j	Storage and junction temperature range			- 40 to + 150	°C

THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R _{th} (j-c)	Junction to case	TO220AC	2.2
		ISOWATT220AC	5.0

ELECTRICAL CHARACTERISTICS

STATIC CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
I _R *	T _j = 25°C	V _R = V _{RWM}				200	μA
	T _j = 100°C					2.0	mA
V _F **	T _j = 25°C	I _F = 6 A				2.0	V
	T _j = 100°C	I _F = 6 A				1.8	

Pulse test : * tp = 5 ms, duty cycle < 2 %

** tp = 380 μs, duty cycle < 2 %

RECOVERY CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
t _{rr} (1)	T _j = 25°C	I _F = 1 A V _R = 30 V	dI _F /dt = -50 A/μs dI _F /dt = -15 A/μs			100	ns
t _{rr} (1)	T _j = 100°C					120	ns
t _{rr}	T _j = 25°C	I _F = 100mA	I _R = 100mA		70		ns

TURN ON SWITCHING CHARACTERISTICS

Symbol	Test Conditions			Min.	Typ.	Max.	Unit
t _{FR} (2)	T _j = 100°C	I _F = 6 A	dI _F /dt = 80 A/μs		0.5		μs
V _{FP} (2)		V _{FR} = 1.1 x V _F			27		V

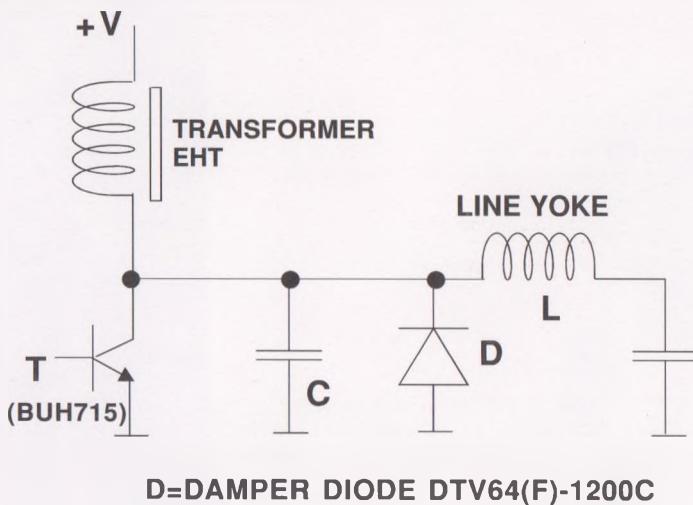
(1) Test following Jedec Standard

(2) Test representative of the application

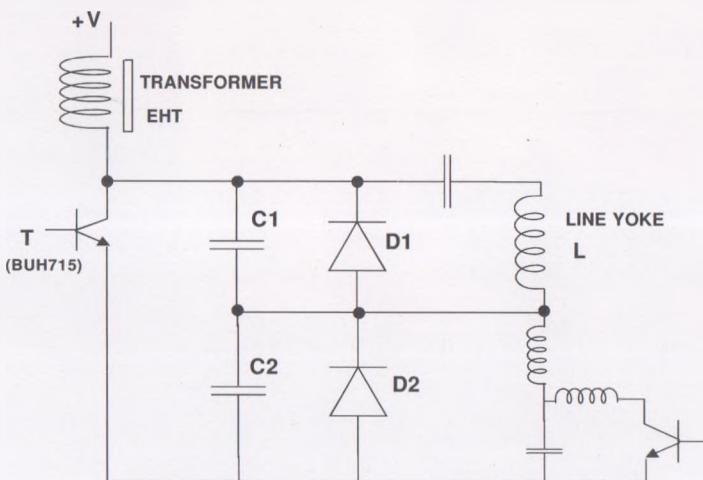
To evaluate the conduction losses use the following equations :

$$V_F = 1.5 + 0.050 \cdot I_F \quad P = 1.5 \times I_{F(AV)} + 0.050 \times I_{F^2(RMS)}$$

BASIC HORIZONTAL DEFLECTION CIRCUIT



BASIC E-W DIODE MODULATOR CIRCUIT



D1=DTV64(F)-1200C

D2=STTB506D/F